

FPAB30BH60B PFC SPM® 3 Series for 1-Phase Boost PFC

Features

- Low Thermal Resistance Thanks to Al₂O₃-DBC Substrate
- 600 V - 30 A 1-Phase Boost PFC Including A Drive IC for Gate Driving and Protection
- Built-In NTC Thermistor for Monitoring Over-Temperature
- Typical Switching Frequency of 20 kHz
- Isolation Rating of 2500 Vrms/min.

Applications

- 1-Phase Boost PFC Converter for Air Conditioner

General Description

FPAB30BH60B Is An Advanced PFC SPM 3 Series for 1-Phase Boost PFC (Power Factor Correction) that Fairchild Has Newly Developed for Mid-Power Applications such as Air Conditioners. It Combines Optimized Circuit Protections and A Drive IC Matched to High Frequency Switching IGBT. The System Reliability Is Further Enhanced by The Integrated Under-Voltage Lock-Out and Over-Current Protection Function.

Related Source

- [Will Be Released](#)

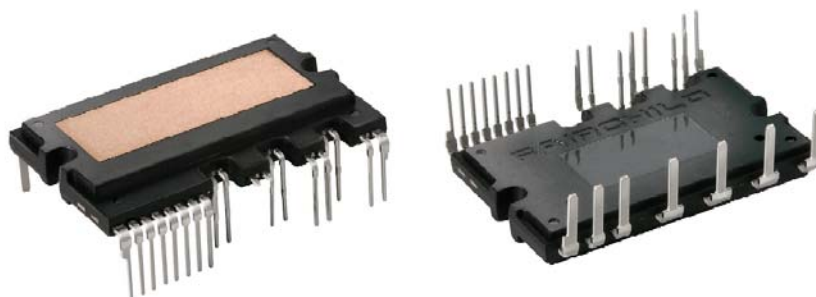


Fig. 1. Package Overview

Package Marking & Ordering Information

Device Marking	Device	Package	Packing Type	Reel Size	Tape Width	Quantity
FPAB30BH60B	FPAB30BH60B	SPMIC-027	RAIL	-	-	10

Integrated Power Functions

- PFC converter for single-phase AC/DC power conversion (Please refer to Fig. 3)

Integrated Drive, Protection and System Control Functions

- For IGBTs : Gate drive circuit, Over Current(OC) protection, Control supply circuit Under-Voltage(UV) protection
- Fault signal : Corresponding to OC and UV fault
- Built-in thermistor: Over-temperature monitoring
- Input interface : Active-high interface, can work with 3.3 / 5 V Logic, Schmitt trigger input

Pin Configuration

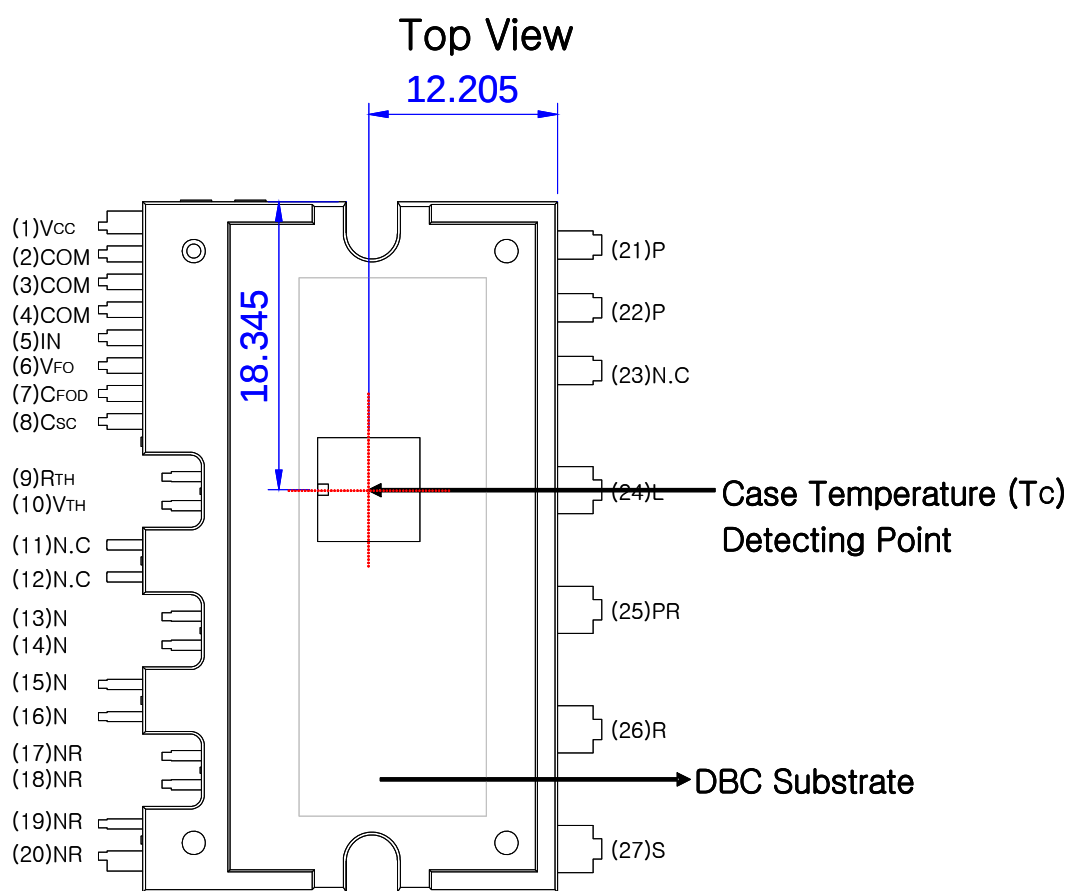


Fig. 2.

Note : For the measurement point of case temperature(T_C), please refer to Fig. 2.

Pin Descriptions

Pin Number	Pin Name	Pin Description
1	V _{CC}	Common Bias Voltage for IC and IGBT Driving
2,3,4	COM	Common Supply Ground
5	IN	Signal Input for IGBT
6	V _{FO}	Fault Output
7	C _{FOD}	Capacitor for Fault Output Duration Time Selection
8	C _{SC}	Capacitor (Low-pass Filter) for Over Current Detection
9	R _(TH)	NTC Thermistor terminal
10	V _(TH)	NTC Thermistor terminal
11,12	N.C	No Connection*
13~16	N	IGBT emitter
17~20	N _R	Negative DC-Link of Rectifier
21,22	P	Positive Rail of DC-Link
23	N.C	No Connection
24	L	Reactor connection pin
25	P _R	Positive DC-Link of Rectifier
26	R	AC input for R-phase
27	S	AC input for S-phase

* 11th and 12th pins are cut. Please refer to package outline drawings for more detail.

Internal Equivalent Circuit and Input/Output Pins

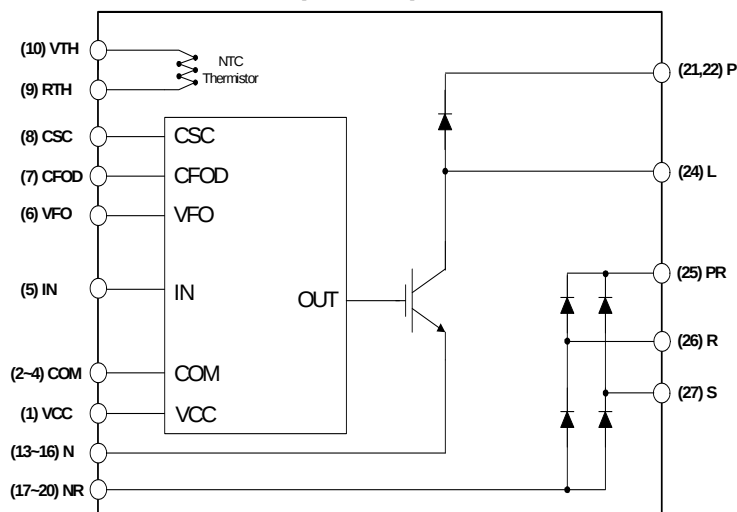


Fig. 3.

Absolute Maximum Ratings ($T_J = 25^{\circ}\text{C}$, Unless Otherwise Specified)**Converter Part**

Item	Symbol	Condition	Rating	Unit
Supply Voltage	V_i	Applied between R-S	264	V_{RMS}
Supply Voltage (Surge)	$V_{i(\text{Surge})}$	Applied between R-S	500	V
Output Voltage	V_{PN}	Applied between P- N	450	V
Output Voltage (Surge)	$V_{\text{PN}(\text{Surge})}$	Applied between P- N	500	V
Collector-emitter Voltage	V_{CES}		600	V
Each IGBT Collector Current	I_{C}	$T_{\text{C}} = 25^{\circ}\text{C}$, $T_J < 150^{\circ}\text{C}$	30	A
Each IGBT Collector Current (peak)	I_{CP}	$T_{\text{C}} = 25^{\circ}\text{C}$, $T_J < 150^{\circ}\text{C}$ Under 1ms pulse width	60	A
Collector Dissipation	P_{C}	$T_{\text{C}} = 25^{\circ}\text{C}$ per One IGBT	104	W
Repetitive Peak Reverse Voltage	V_{RRM}		600	V
Peak Forward Surge Current	I_{FSM}	Single half sine-wave	350	A
Operating Junction Temperature	T_J		-40 ~ 150	$^{\circ}\text{C}$

Control Part

Item	Symbol	Condition	Rating	Unit
Control Supply Voltage	V_{CC}	Applied between V_{CC} - COM	20	V
Input Signal Voltage	V_{IN}	Applied between IN - COM	-0.3~ $V_{\text{CC}}+0.3$	V
Fault Output Supply Voltage	V_{FO}	Applied between V_{FO} - COM	-0.3~ $V_{\text{CC}}+0.3$	V
Fault Output Current	I_{FO}	Sink Current at V_{FO} Pin	5	mA
Current Sensing Input Voltage	V_{SC}	Applied between C_{SC} - COM	-0.3~ $V_{\text{CC}}+0.3$	V

Total System

Item	Symbol	Condition	Rating	Unit
Storage Temperature	T_{STG}		-40 ~ 125	$^{\circ}\text{C}$
Isolation Voltage	V_{ISO}	60 Hz, Sinusoidal, AC 1 minute, Connection Pins to DBC	2500	V_{rms}

Thermal Resistance

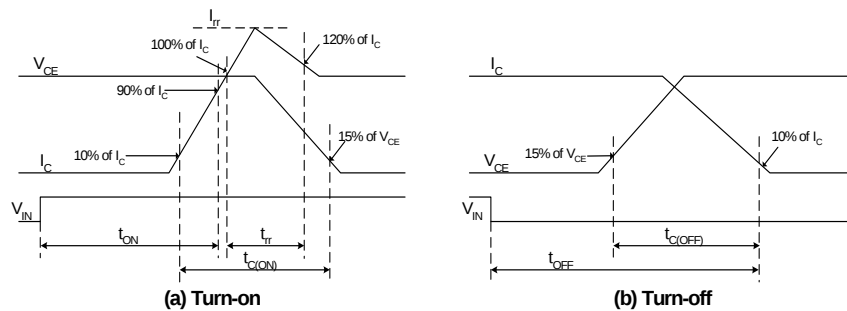
Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Junction to Case Thermal Resistance	$R_{\theta(j-c)Q}$	IGBT	-	-	1.2	$^{\circ}\text{C/W}$
	$R_{\theta(j-c)F}$	FRD	-	-	1.4	$^{\circ}\text{C/W}$
	$R_{\theta(j-c)R}$	Rectifier	-	-	1.7	$^{\circ}\text{C/W}$

Electrical Characteristics ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified)**Converter Part**

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
IGBT saturation voltage	$V_{CE(sat)}$	$V_{CC} = 15\text{ V}$, $V_{IN} = 5\text{ V}$; $I_C = 30\text{ A}$	-	2.2	2.8	V
FRD forward voltage	V_{FF}	$I_F = 30\text{ A}$	-	1.9	2.6	V
Rectifier forward voltage	V_{FR}	$I_F = 30\text{ A}$	-	1.2	1.5	V
Switching Times	t_{ON}	$V_{PN} = 400\text{ V}$, $V_{CC} = 15\text{ V}$, $I_C = 30\text{ A}$ $V_{IN} = 0\text{ V} \leftrightarrow 5\text{ V}$, Inductive Load (Note 1)	-	500	-	ns
	$t_{C(ON)}$		-	200	-	ns
	t_{OFF}		-	420	-	ns
	$t_{C(OFF)}$		-	100	-	ns
	t_{rr}		-	60	-	ns
	I_{rr}		-	7	-	A
Collector - emitter Leakage Current	I_{CES}	$V_{CE} = V_{CES}$	-	-	250	μA

Note

1. t_{ON} and t_{OFF} include the propagation delay time of the internal drive IC. $t_{C(ON)}$ and $t_{C(OFF)}$ are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Fig. 4

Electrical Characteristics**Fig. 4. Switching Time Definition****Control Part**

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Quiescent V_{CC} Supply Current	I_{QCCL}	$V_{CC} = 15\text{ V}$, $I_N = 0\text{ V}$ $V_{CC} - \text{COM}$	-	-	26	mA
Fault Output Voltage	V_{FOH}	$V_{SC} = 0\text{ V}$, V_{FO} Circuit: 4.7 k Ω to 5 V Pull-up	4.5	-	-	V
	V_{FOL}	$V_{SC} = 1\text{ V}$, V_{FO} Circuit: 4.7 k Ω to 5 V Pull-up	-	-	0.8	V
Over Current Trip Level	$V_{SC(ref)}$	$V_{CC} = 15\text{ V}$	0.45	0.5	0.55	V
Supply Circuit Under-Voltage Protection	UV_{CCD}	Detection Level	10.7	11.9	13.0	V
	UV_{CCR}	Reset Level	11.2	12.4	13.2	V
Fault-out Pulse Width	t_{FOD}	$C_{FOD} = 33\text{ nF}$ (Note 2)	1.4	1.8	2.0	ms
ON Threshold Voltage	$V_{IN(ON)}$	Applied between IN - COM	2.8	-	-	V
OFF Threshold Voltage	$V_{IN(OFF)}$		-	-	0.8	V
Resistance of Thermistor	R_{TH}	@ $T_{TH} = 25^\circ\text{C}$ (Note3, Fig. 9)	-	47.0	-	k Ω
		@ $T_{TH} = 100^\circ\text{C}$ (Note3, Fig. 9)	-	2.9	-	k Ω

Note

2. The fault-out pulse width t_{FOD} depends on the capacitance value of C_{FOD} according to the following approximate equation : $C_{FOD} = 18.3 \times 10^{-6} \times t_{FOD} [F]$
 3. T_{TH} is the temperature of know case temperature(T_C), please make the experiment considering your application.

Recommended Operating Condition

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Input Supply Voltage	V_i	Applied between R-S	187	220	253	V
Output Voltage	V_{PN}	Applied between P-N		380	400	V
Control Supply Voltage	V_{CC}	Applied between $V_{CC(L)}$ - COM	13.5	15	16.5	V
Control supply variation	dV_{CC}/dt		-1	-	1	V/ μ s
PWM Input Frequency	f_{PWM}	$T_J \leq 150^\circ\text{C}$ per IGBT		20		kHz
Allowable Input Current (Peak)	I_i	$T_C < 90^\circ\text{C}$, $V_i = 220\text{ V}$, $V_{PN} = 380\text{ V}$ $V_{PWM} = 20\text{ kHz}$			30	A

Mechanical Characteristics and Ratings

Item	Condition	Limit			Unit
		Min.	Typ.	Max.	
Mounting Torque	Mounting Screw: M3 Recommended 0.62 N•m	0.51	0.62	0.72	N•m
Device Flatness	Note Fig. 5	0	-	+120	μ m
Weight		-	15.00	-	g

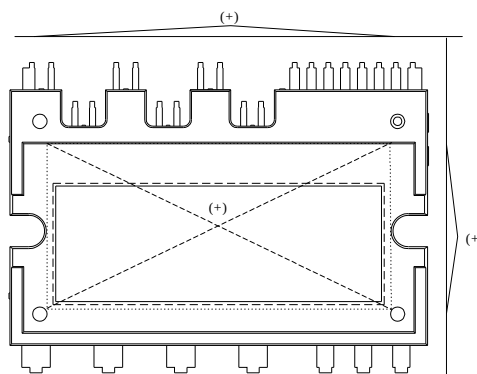
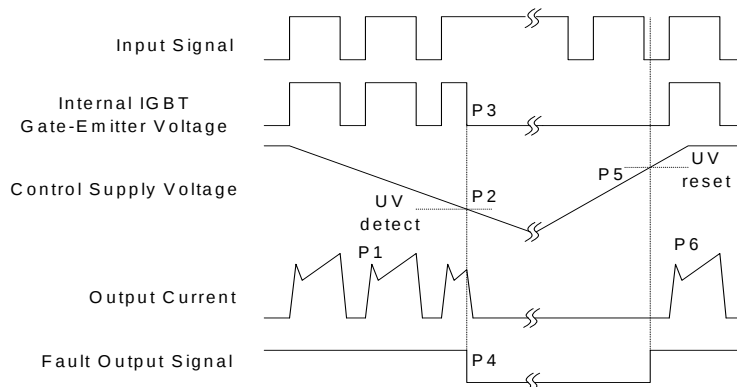


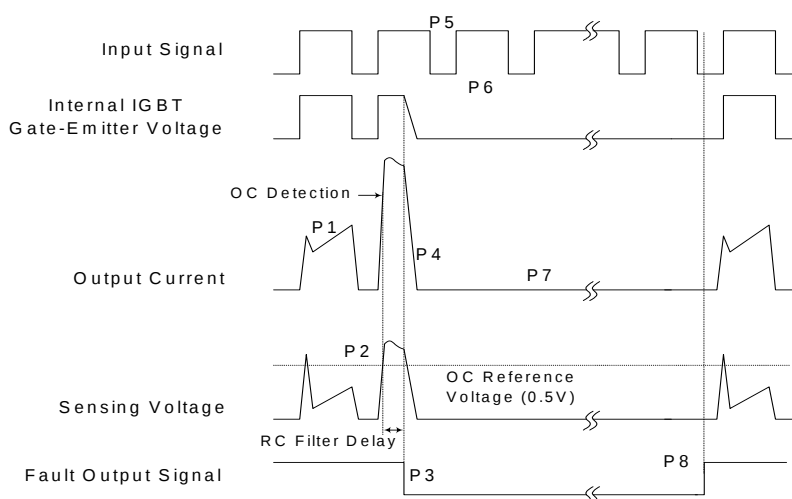
Fig. 5. Flatness Measurement Position

Time Charts of SPMs Protective Function



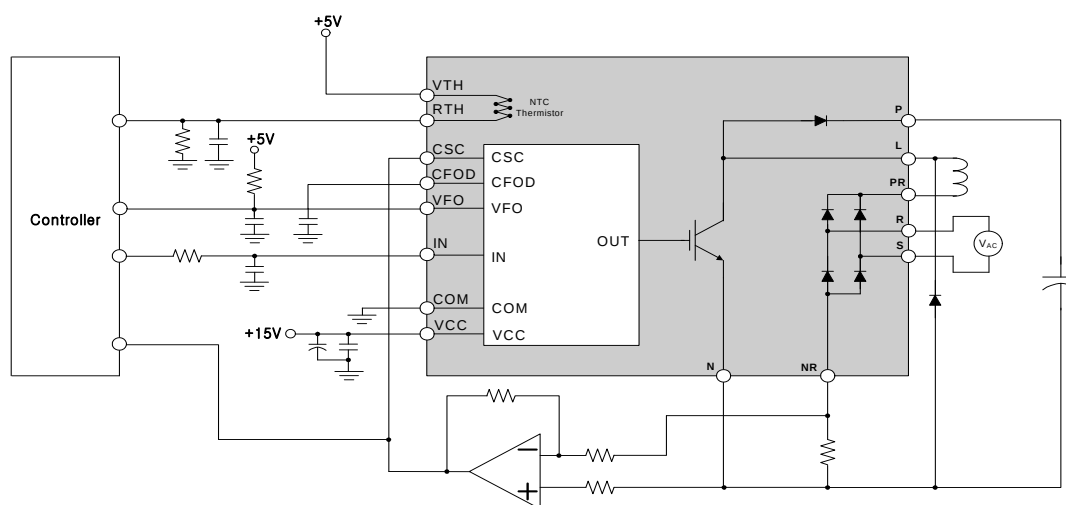
- P1 : Normal operation - IGBT ON and conducting current
P2 : Under voltage detection
P3 : IGBT gate interrupt
P4 : Fault signal generation
P5 : Under voltage reset
P6 : Normal operation - IGBT ON and conducting current

Fig. 6. Under-Voltage Protection



- P1 : Normal operation - IGBT ON and conducting current
P2 : Over current detection
P3 : IGBT gate interrupt / Fault signal generation
P4 : IGBT is slowly turned off
P5 : IGBT OFF signal
P6 : IGBT ON signal - but IGBT cannot be turned on during the fault Output activation
P7 : IGBT OFF state
P8 : Fault Output reset and normal operation start

Fig. 7. Over Current Protection



Note:

1. Each capacitors should be located as close to PFC SPM® product pins as possible.
2. It's recommended that anti-parallel diode should be connected with IGBT.

Fig. 8. Application Example

R-T Curve

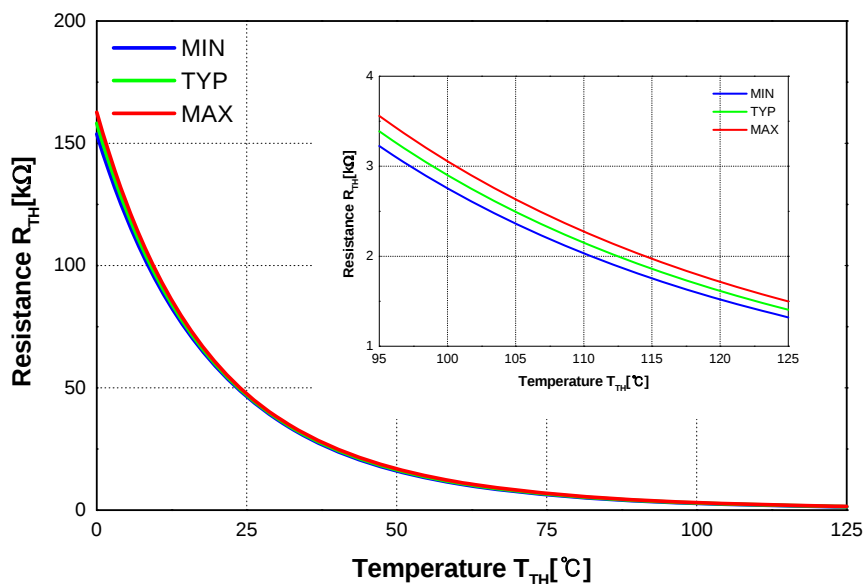
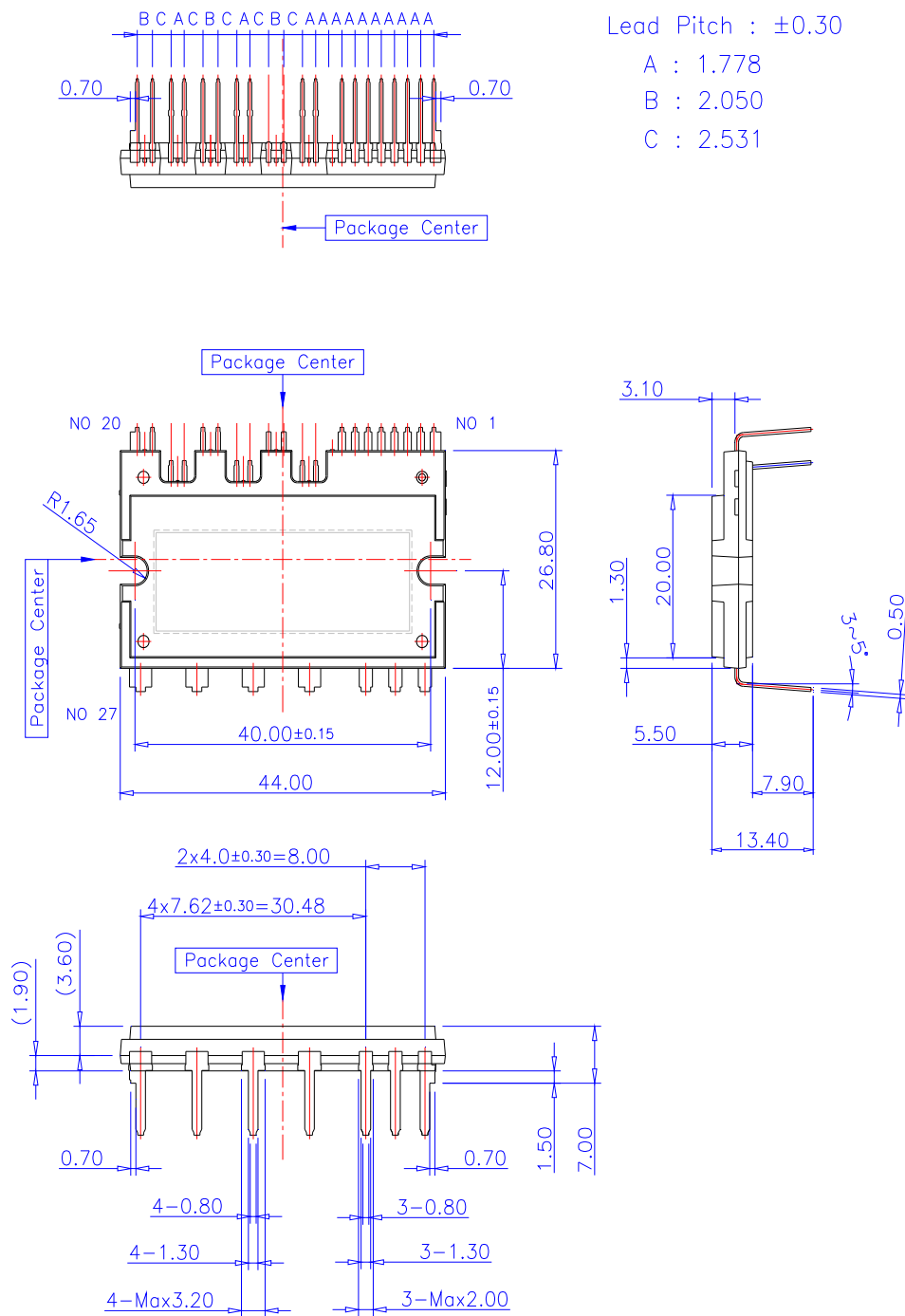
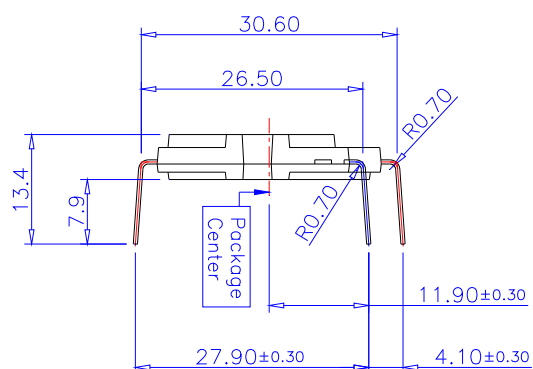


Fig. 9. R-T Curve of the Built-in Thermistor

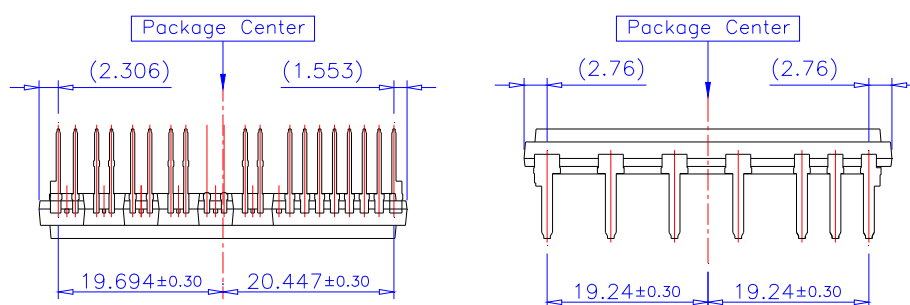
Detailed Package Outline Drawings



Detailed Package Outline Drawings

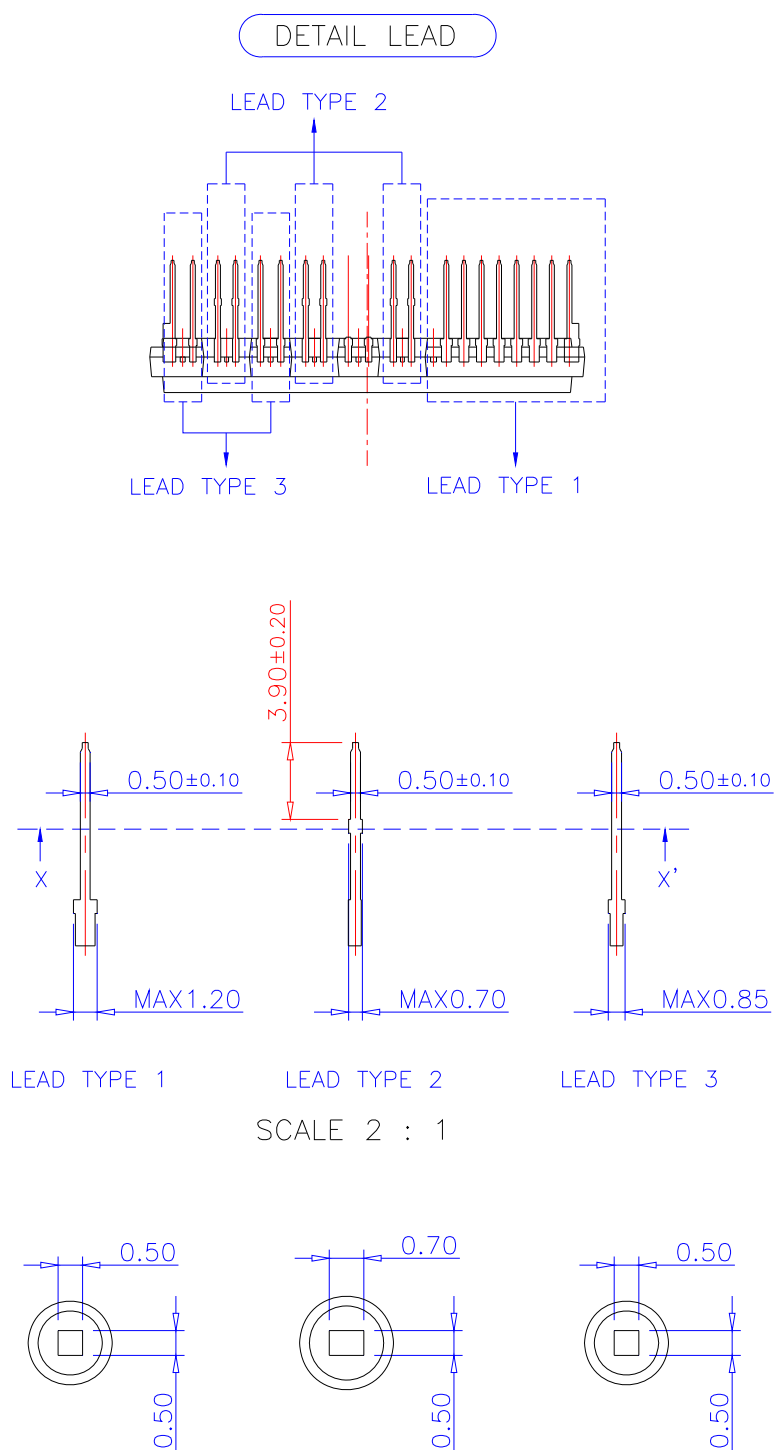


Lead Forming Dimension



PKG Center to Lead Distance

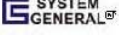
Detailed Package Outline Drawings





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